

2MBI450XEE120-50

IGBT Modules

Power Module (X series)
1200V / 450A / 2-in-1 package

■ **Features**

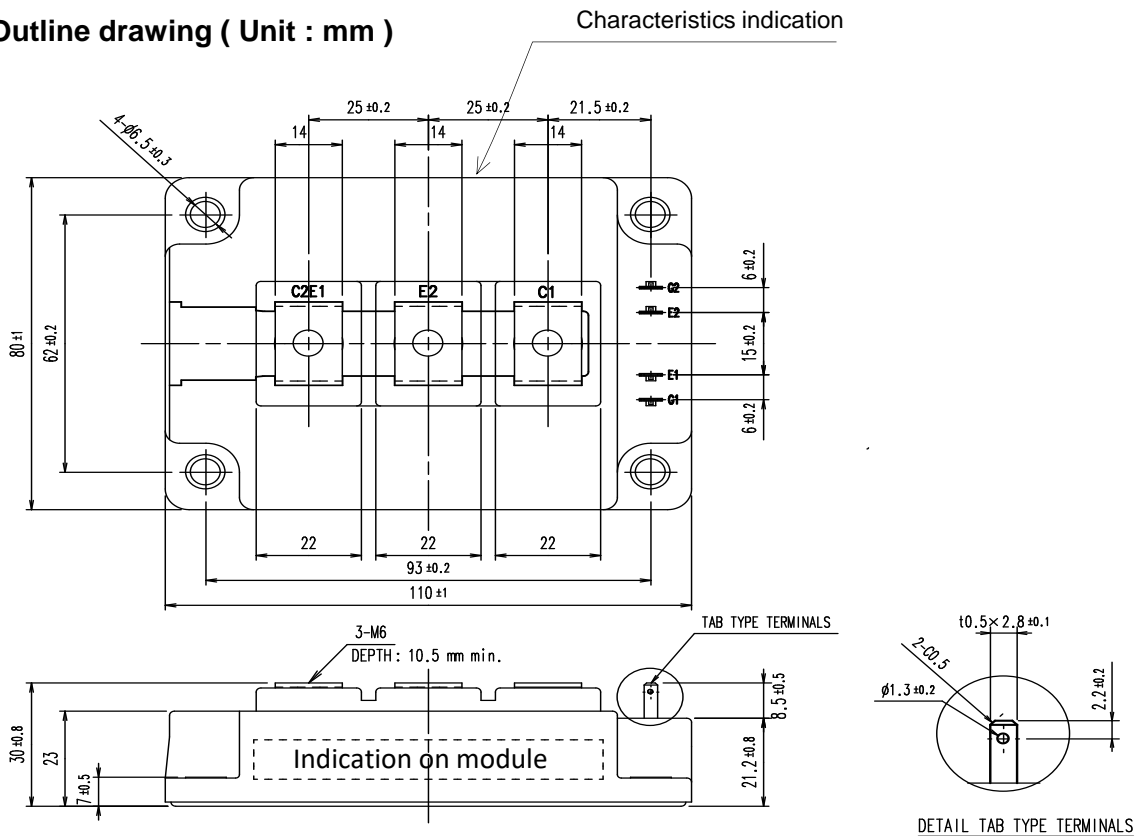
- LOW $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines

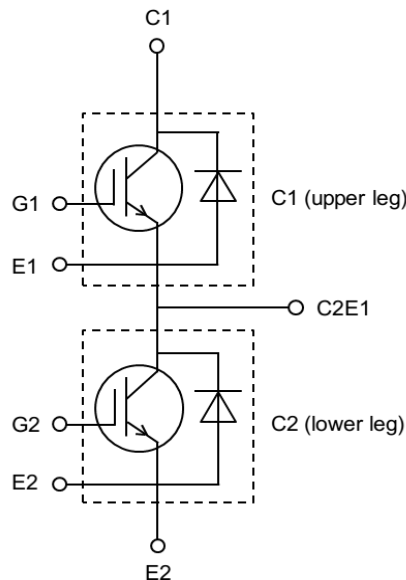


■ **Outline drawing (Unit : mm)**



Weight: 470 g(typ.)

■ **Equivalent Circuit**



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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Collector-Emitter cut -off current, Gate-Emitter short - circuited	I_{CES}	$V_{GE} = 0V$ $V_{CE} = 1200V$	-	-	200	μA	
Gate leakage current, Collector-Emitter short-circuited	I_{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	400	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 450\text{mA}$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 450A$	$T_{vj}=25^{\circ}\text{C}$	-	1.65	2.10	V
			$T_{vj}=25^{\circ}\text{C}$	-	1.45	1.90	
	$T_{vj}=125^{\circ}\text{C}$		-	1.85	-		
	$T_{vj}=150^{\circ}\text{C}$		-	1.90	-		
	$T_{vj}=175^{\circ}\text{C}$		-	2.00	-		
Internal gate resistance	r_g	-	-	2.25	-	Ω	
			-	46	-	nF	
Input capacitance	C_{ies}	$V_{CE}=10V, V_{GE}=0V, f=1\text{MHz}$	-	1.6	-		
Output capacitance	C_{oes}		-	0.42	-		
Reverse transfer capacitance	C_{res}		-	-	-		
Gate charge	Q_G	$V_{CC} = 600V, I_C = 450A$ $V_{GE} = -15 \rightarrow +15V$	-	2950	-	nC	
Forward voltage	V_F (terminal)	$V_{GE} = 0V$ $I_F = 450A$	$T_{vj}=25^{\circ}\text{C}$	-	1.85	2.30	V
			$T_{vj}=25^{\circ}\text{C}$	-	1.65	2.10	
	$T_{vj}=125^{\circ}\text{C}$		-	1.65	-		
	$T_{vj}=150^{\circ}\text{C}$		-	1.65	-		
	$T_{vj}=175^{\circ}\text{C}$		-	1.60	-		
Turn-on delay time (*1)	$t_{d(on)}$	$V_{CC} = 600V$ $I_C, I_F = 450A$ $V_{GE} = +15/ -15V$ $R_G = 1 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	350	-	ns
			$T_{vj}=125^{\circ}\text{C}$	-	390	-	
			$T_{vj}=150^{\circ}\text{C}$	-	400	-	
			$T_{vj}=175^{\circ}\text{C}$	-	415	-	
			$T_{vj}=25^{\circ}\text{C}$	-	85	-	
Rise time (*1)	t_r		$T_{vj}=125^{\circ}\text{C}$	-	110	-	
			$T_{vj}=150^{\circ}\text{C}$	-	115	-	
			$T_{vj}=175^{\circ}\text{C}$	-	110	-	
			$T_{vj}=25^{\circ}\text{C}$	-	340	-	
Turn-off delay time (*1)	$t_{d(off)}$		$T_{vj}=125^{\circ}\text{C}$	-	380	-	
			$T_{vj}=150^{\circ}\text{C}$	-	390	-	
			$T_{vj}=175^{\circ}\text{C}$	-	390	-	
			$T_{vj}=25^{\circ}\text{C}$	-	140	-	
Fall time (*1)	t_f		$T_{vj}=125^{\circ}\text{C}$	-	210	-	
			$T_{vj}=150^{\circ}\text{C}$	-	225	-	
			$T_{vj}=175^{\circ}\text{C}$	-	245	-	
			$T_{vj}=25^{\circ}\text{C}$	-	235	-	
Reverse recovery time	t_{rr}		$T_{vj}=125^{\circ}\text{C}$	-	560	-	
			$T_{vj}=150^{\circ}\text{C}$	-	640	-	
			$T_{vj}=175^{\circ}\text{C}$	-	690	-	

(*1) Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

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■ Electrical characteristics (at $T_{vj}= 25^{\circ}\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Turn-on energy	E_{on}	$V_{CC} = 600\text{V}$ $I_C, I_F = 450\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 1\ \Omega$ $L_S = 30\ \text{nH}$	$T_{vj}=25^{\circ}\text{C}$	-	36.7	-	mJ
			$T_{vj}=125^{\circ}\text{C}$	-	55.7	-	
			$T_{vj}=150^{\circ}\text{C}$	-	60.4	-	
			$T_{vj}=175^{\circ}\text{C}$	-	66.8	-	
Turn-off energy	E_{off}		$T_{vj}=25^{\circ}\text{C}$	-	29.4	-	
			$T_{vj}=125^{\circ}\text{C}$	-	37.8	-	
			$T_{vj}=150^{\circ}\text{C}$	-	39.9	-	
			$T_{vj}=175^{\circ}\text{C}$	-	40.7	-	
Reverse recovery energy	E_{rr}		$T_{vj}=25^{\circ}\text{C}$	-	10.4	-	
			$T_{vj}=125^{\circ}\text{C}$	-	19.9	-	
			$T_{vj}=150^{\circ}\text{C}$	-	22.3	-	
			$T_{vj}=175^{\circ}\text{C}$	-	25.7	-	

NOTICE:

The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

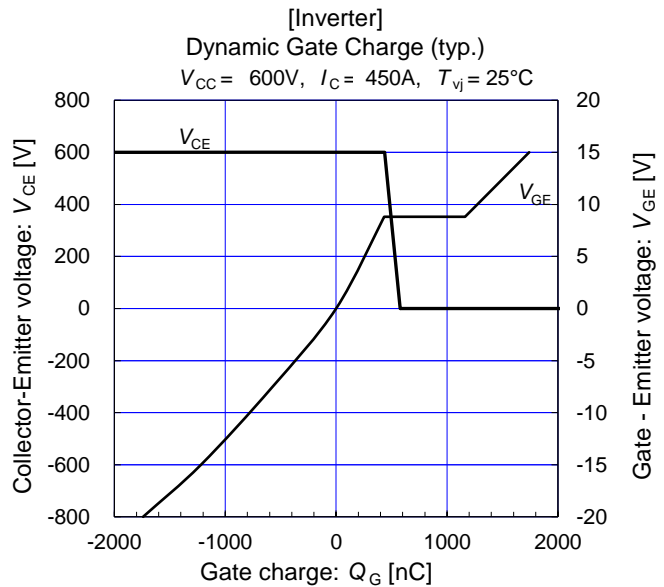
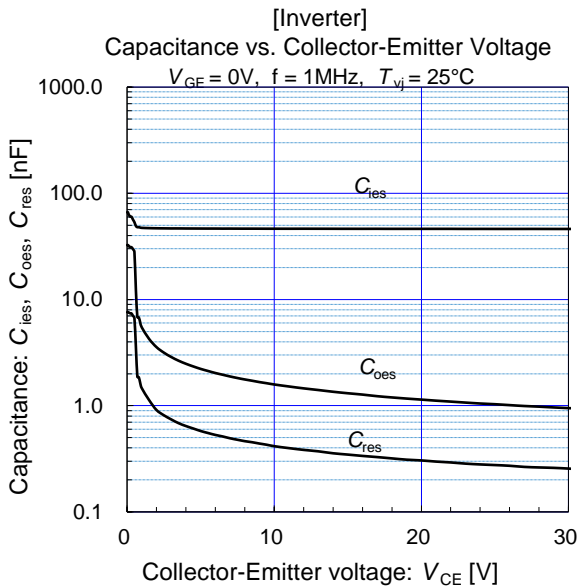
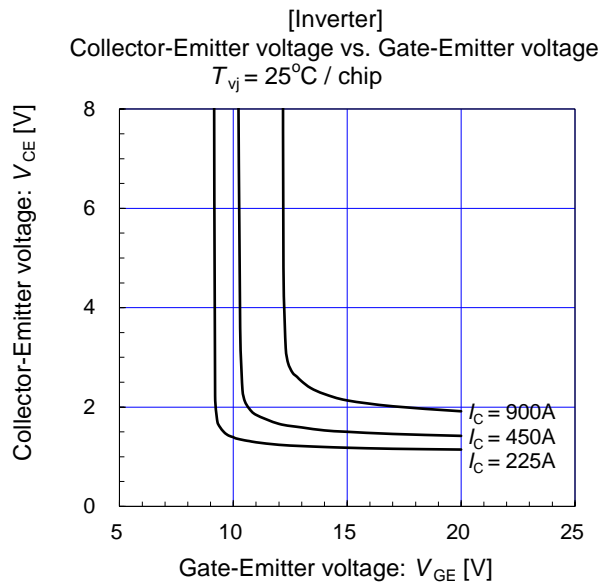
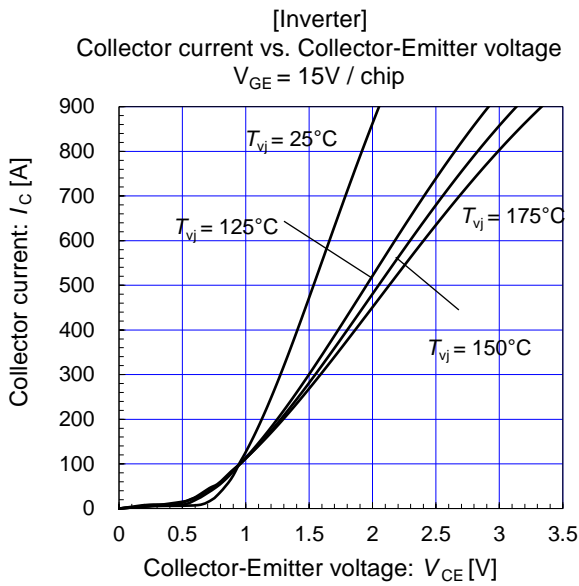
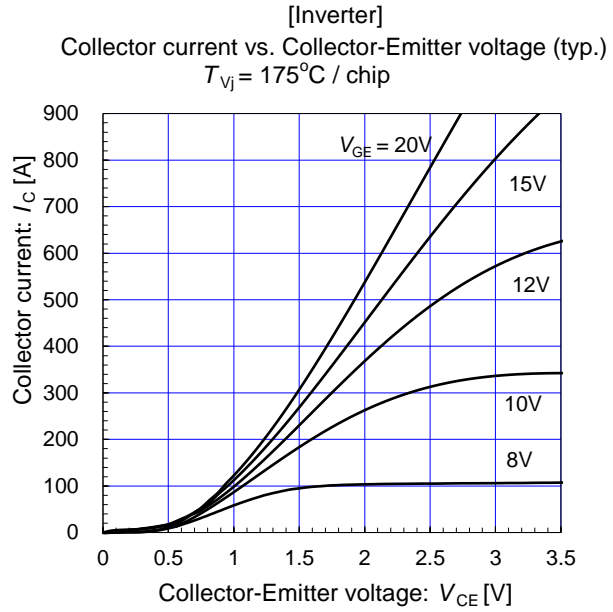
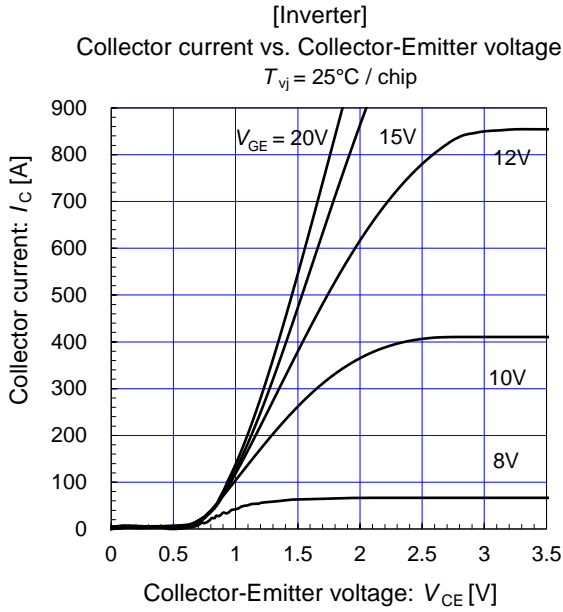
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.050	K/W
		Inverter FWD	-	-	0.084	
Thermal resistance case to heat sink (1IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.0125	-	

(*1) This is the value which is defined mounting on the additional heat sink with thermal grease.

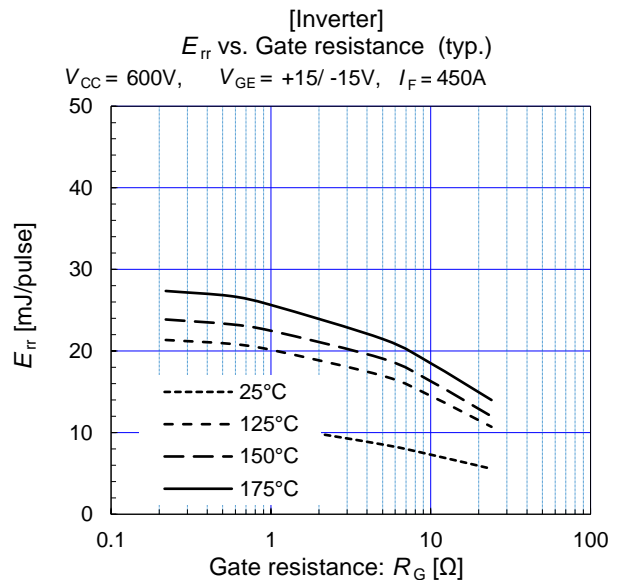
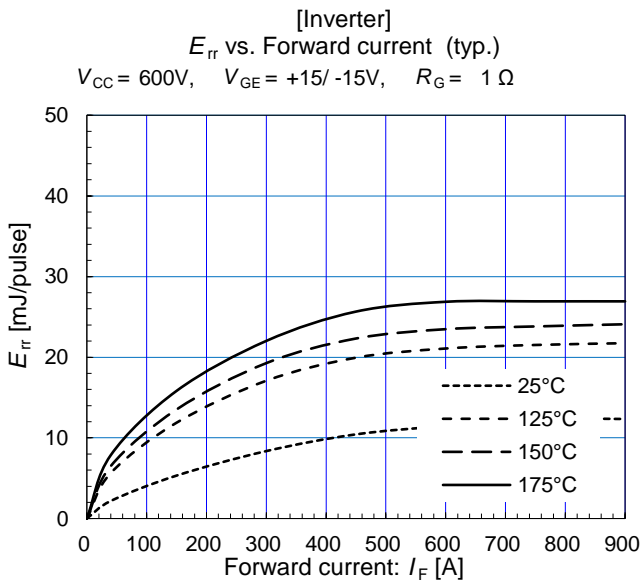
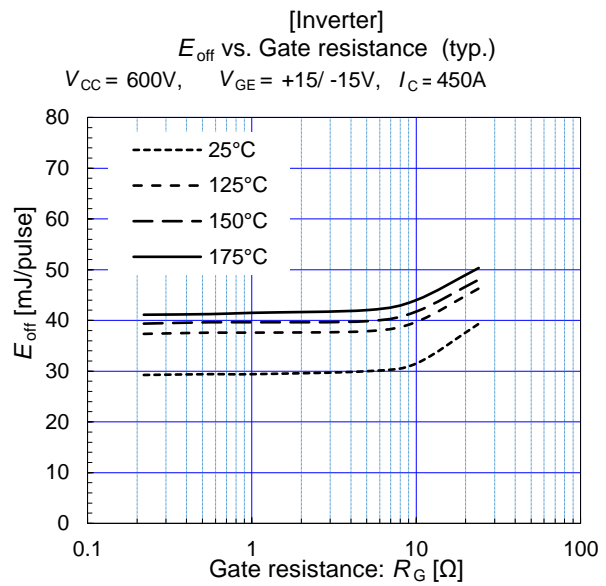
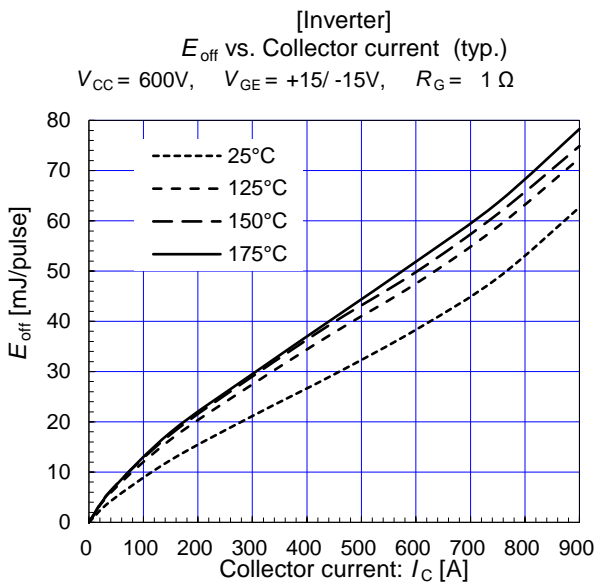
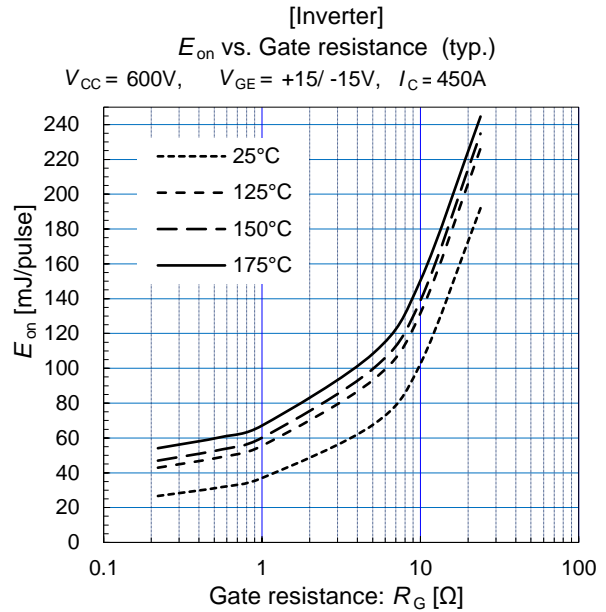
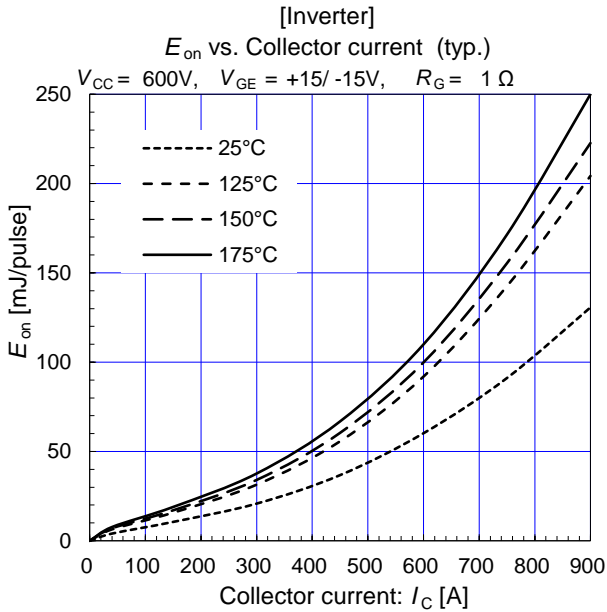
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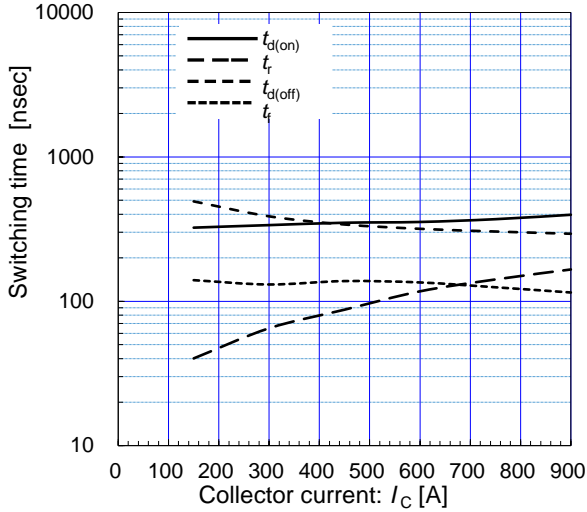
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[Inverter]

Switching time vs. Collector current (typ.)

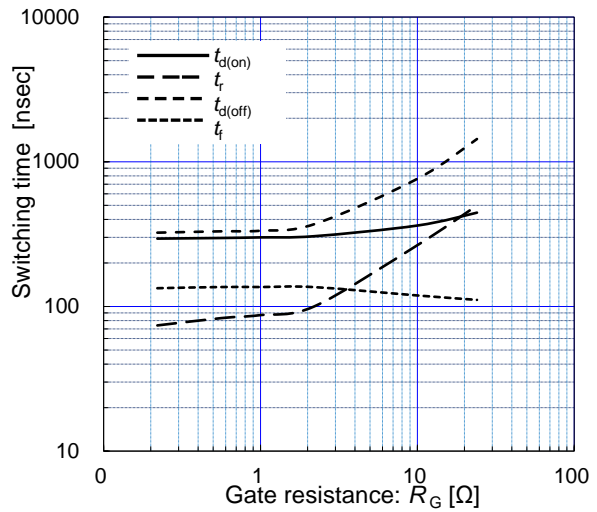
$V_{CC} = 600V, R_G = 1\Omega, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

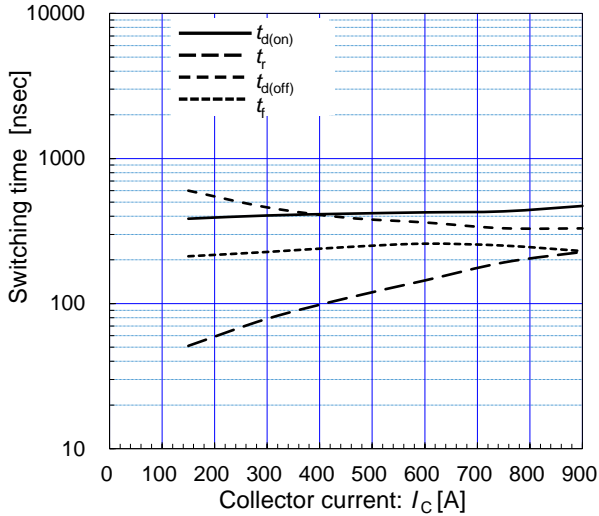
$V_{CC} = 600V, I_C = 450A, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Collector current (typ.)

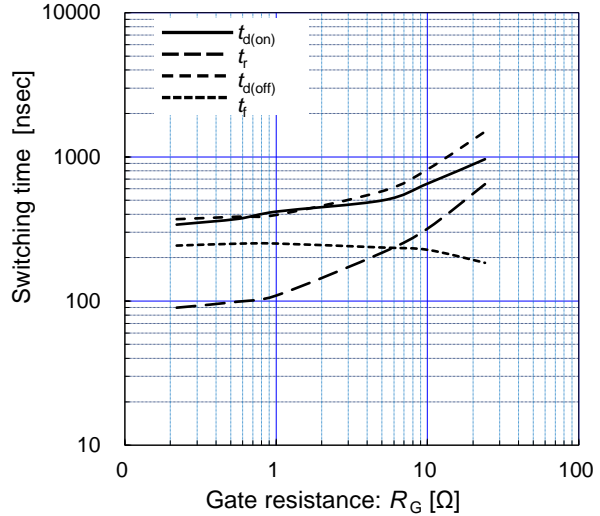
$V_{CC} = 600V, R_G = 1\Omega, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

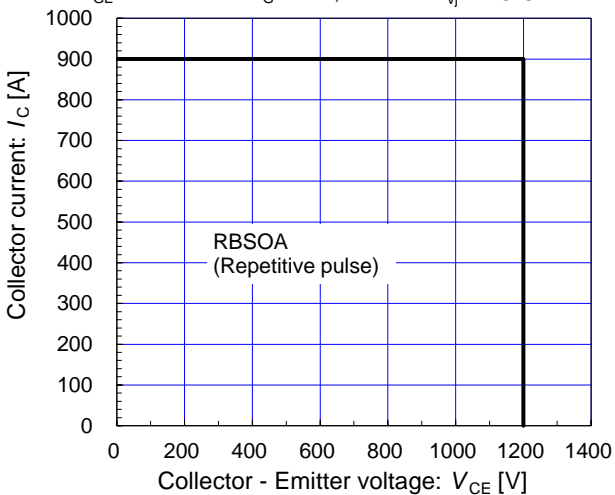
$V_{CC} = 600V, I_C = 450A, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

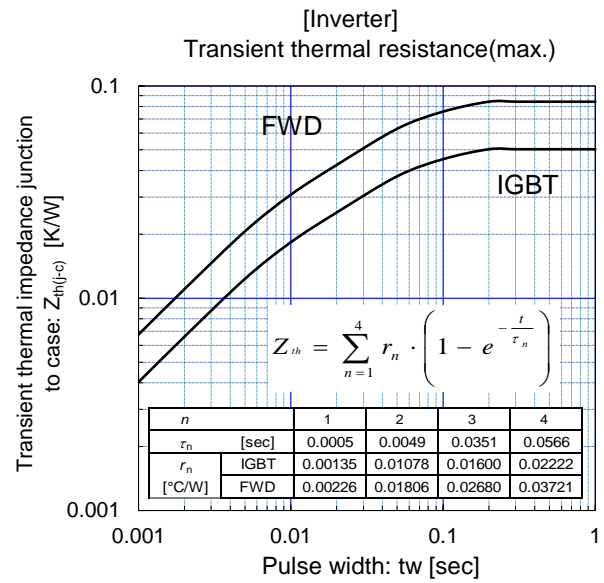
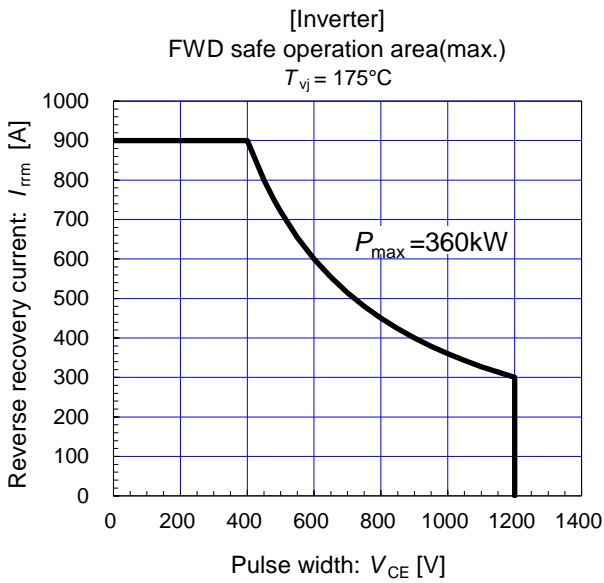
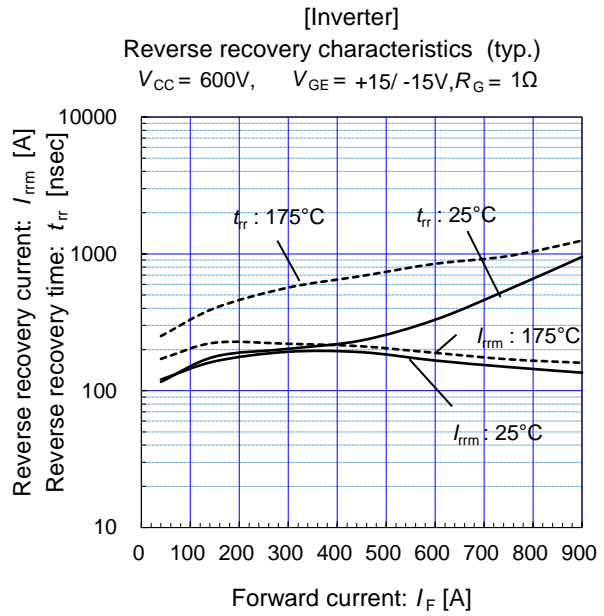
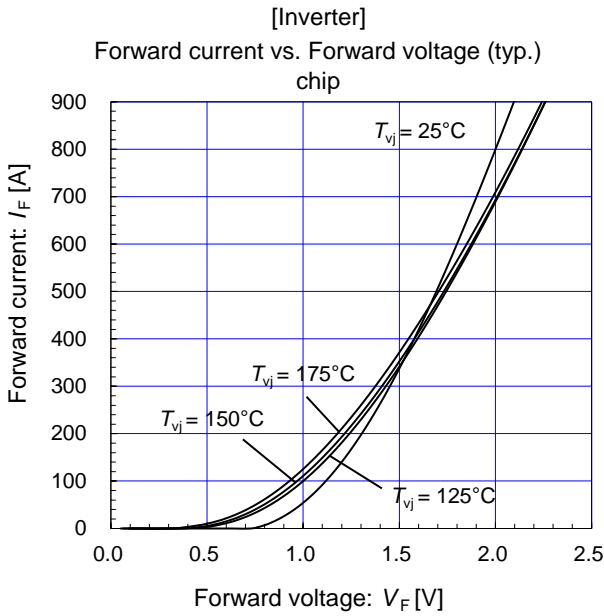
Reverse bias safe operating area (max.)

$V_{GE} = +15/-15V, R_G = 1\Omega, T_{vj} = 175^\circ C$



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